

## CMY 210 - 880 MHz to 85 MHz Down-Converter

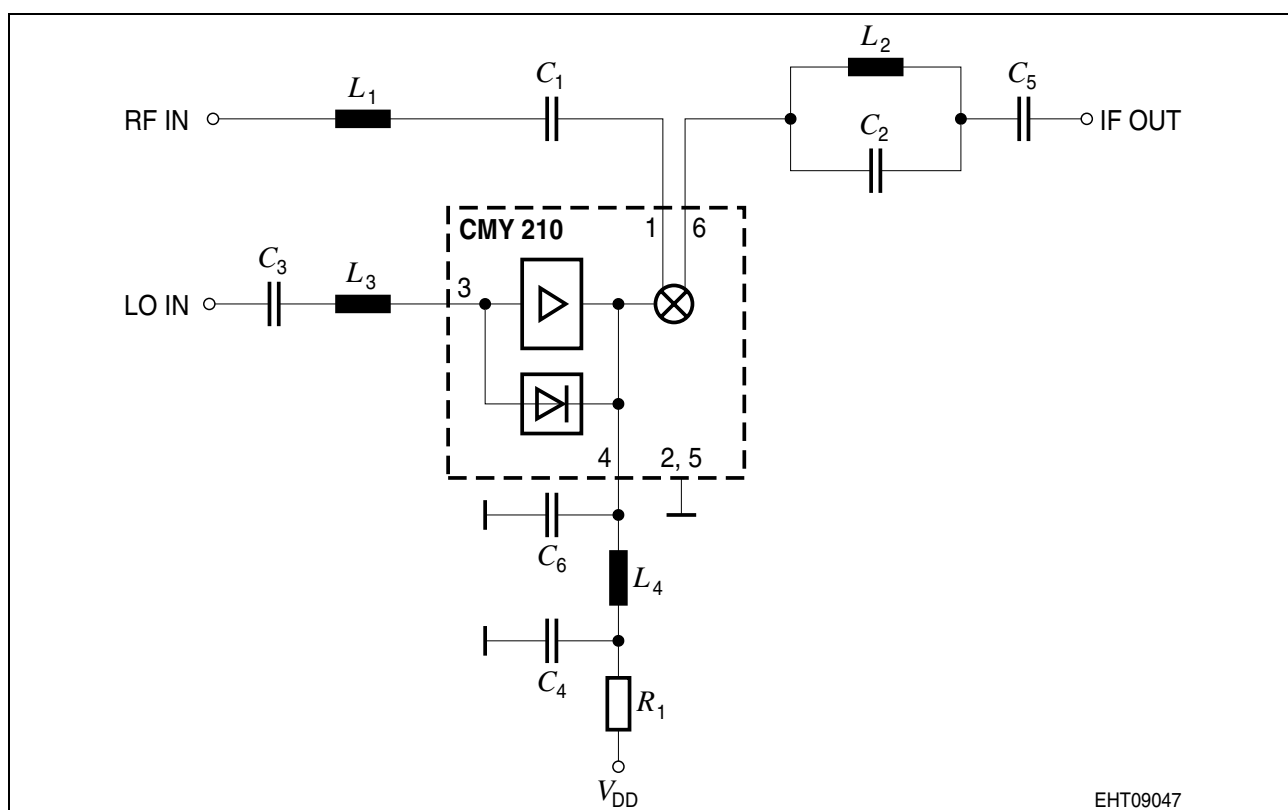
## Application Note No. 038

The CMY 210 is a ultralinear mixer with integrated LO-buffer for frequencies up to and exceeding 2.5 GHz. A low LO-input power of typically 0 dBm is sufficient to provide a very high input intercept point of typically 25 dBm at 3 V.

The input and output ports are 50  $\Omega$  matched. The device can be used as up- and down-converter.

### Application Circuit

The mixer CMY 210 itself consists of a GaAs-FET used as a passive switch in parallel to the signal path. The LO-input power is amplified by a controlled amplifier which improves the overall performance.



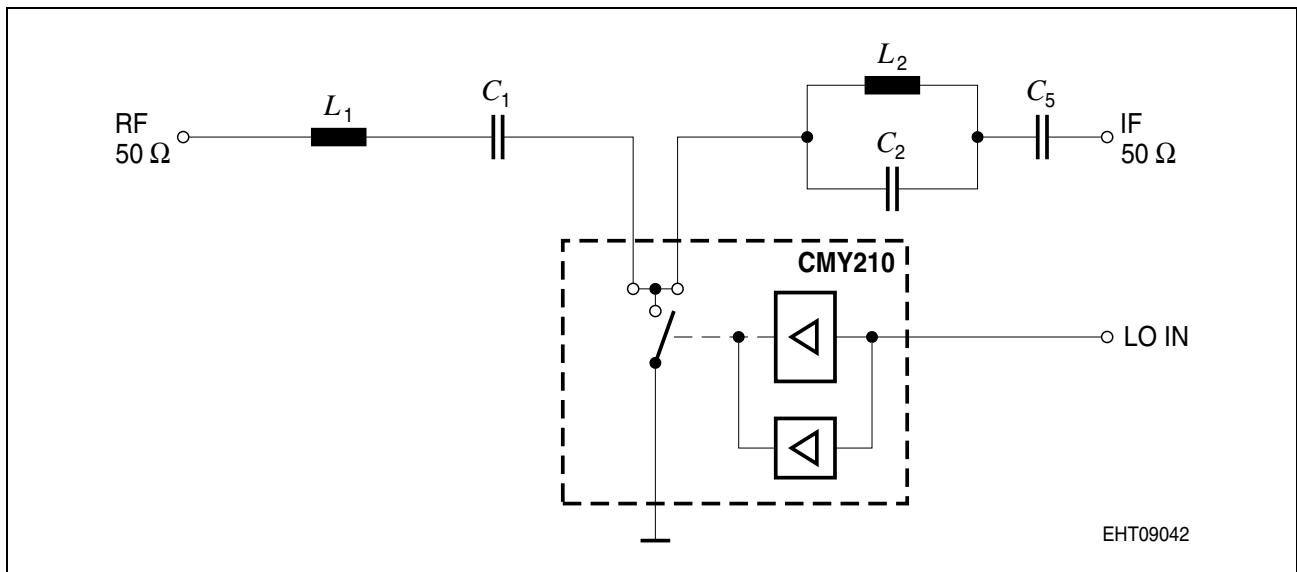
**Figure 1** Application Circuit

**Table 1** List of Components

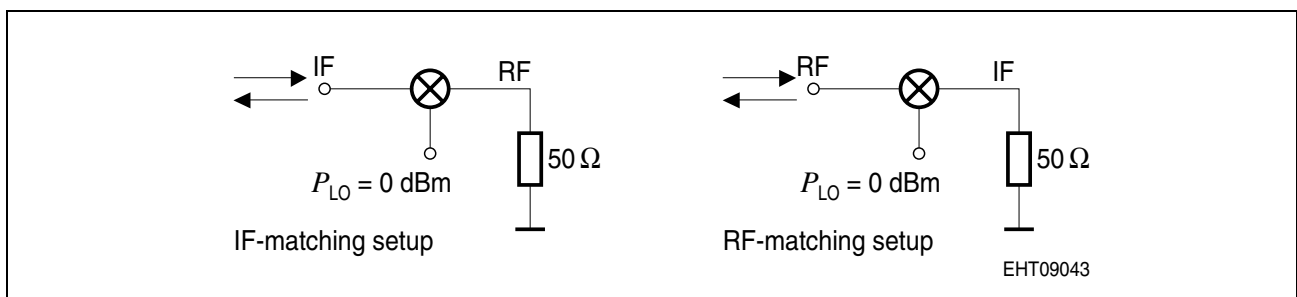
$L_1$	8.2 nH Coilcraft 0805	$C_2$	3.9 pF 0603
$L_2$	8.2 nH Coilcraft 0805	$C_3$	33 pF 0603
$L_3$	6.8 nH Coilcraft 0805	$C_4$	33 pF 0603 parallel to 1 nF 0805 and 1 $\mu$ F
$L_4$	15 nH Coilcraft 0805	$C_5, C_6$	Not required in this application
$C_1$	3.9 pF 0603	$R_1$	Not required in this application

## Setup

1. In order to optimize power consumption,  $L_4$  can be modified for minimum drain current: Switch on the local oscillator at the required LO-frequency and check the drain current. Adjust the LO-frequency to find the minimum current. If the minimum is detected at a lower frequency than the required LO-frequency, choose a lower value inductor for  $L_4$ ; if detected at a higher frequency, choose a higher value.
2. Matching of IF- and RF-filters



**Figure 2** CMY 210 External Matching Circuit



**Figure 3** IF-Matching Setup and RF-Matching Setup

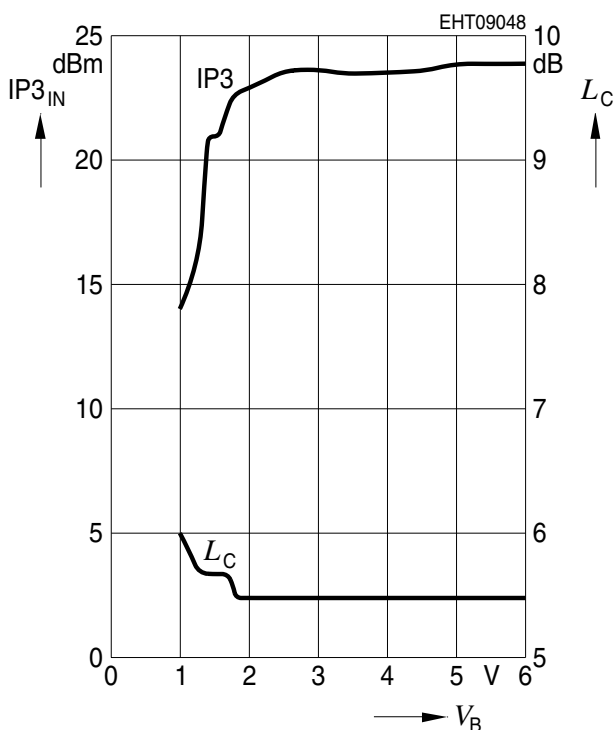
Usually both resonance filters ( $L_1, C_1$  and  $L_2, C_2$ ) are tuned to the RF-frequency. Filter  $L_1, C_1$  passes the RF-frequency and reflects the IF-signal. Filter  $L_2, C_2$  suppresses the RF-band and passes IF. An appropriate adjustment of the filters is the prerequisite to achieve a lower conversion loss. According to [Figure 2](#) the resonance frequency of the IF-filter  $L_2, C_2$  ( $f_{\text{res}} = 1/(2\pi\sqrt{L_2 \times C_2})$ ) can be adjusted to maximum reflection at  $f_{\text{RF}}$  by choosing appropriate inductors and capacitors. Correspondingly, the  $L_1, C_1$  resonance frequency of RF-filter can be matched with minor modification of these values according to [Figure 2](#). Since the IF- and RF-filters are connected with the ohmic resistor of the switching FET, matching of either filter might influence the matching parameters of the other filter.

3. At higher LO-frequencies ( $> 2$  GHz) the gain of the LO buffer amplifier is already decreasing, causing a slightly lower  $IP_{3IN}$  and higher operating current.
4. The  $IP_{3IN}$  remains very constant with changes in operating voltage. A supply voltage of less than 2 V however will decrease the intermodulation performance. Please refer to the following figure. The conversion losses  $L_C$  are independent of the operating voltage as long as the switch transistor is not pinched off. The losses are mainly determined by the quality of IF- and RF-filters as mentioned in 2.

### $IP_{3IN}$ , $L_C$ vs. Operation Voltage

$f_{RF} = 880$  MHz,  $P_{RF} = 2x-3$  dBm,

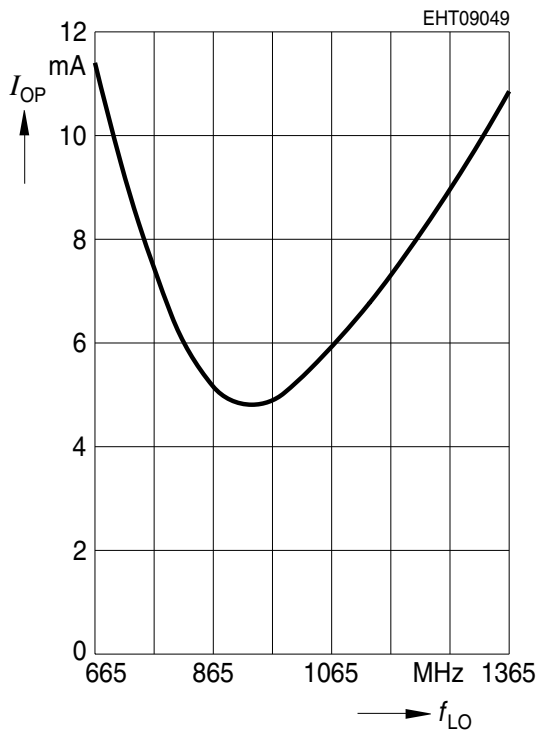
$f_{LO} = 965$  MHz,  $P_{LO} = 0$  dBm



5. The figure below shows the operating current over LO-frequency. A current minimum at approximately 965 MHz has been obtained by tuning the circuit for this LO-frequency as described in 2.

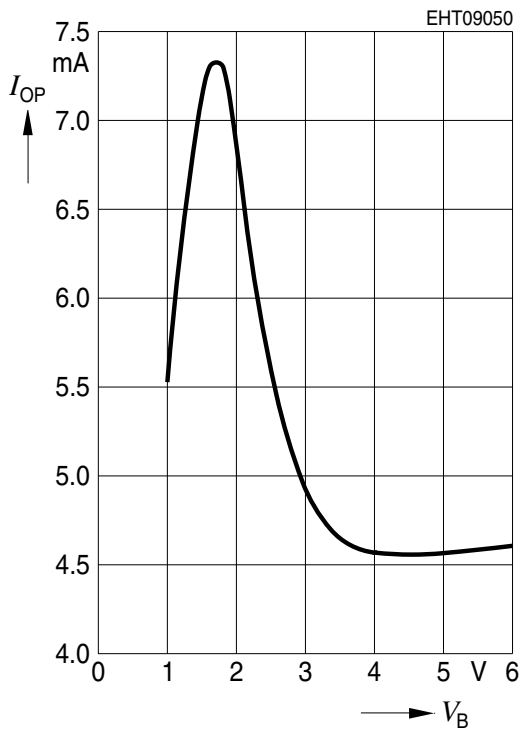
### Operating Current vs. LO-Frequency

$V_D = 3 \text{ V}$ ,  $P_{LO} = 0 \text{ dBm}$

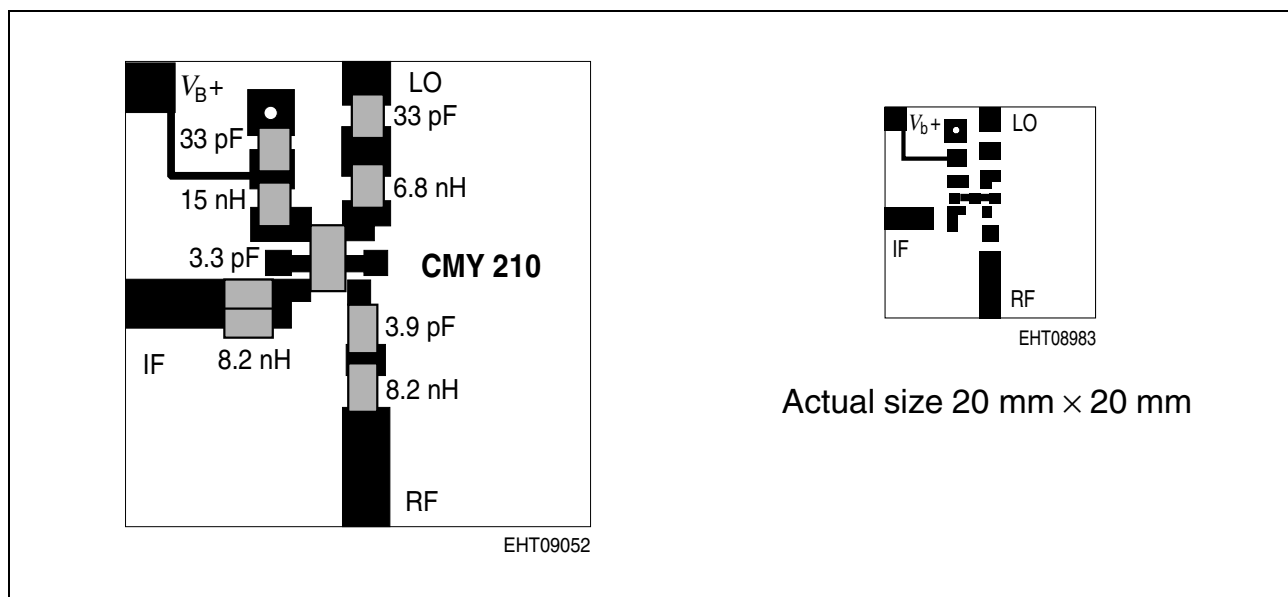


6. The operation current over the operating voltage at a fixed  $f_{LO} = 965$  MHz is shown in the following figure.

### Operation Current vs. Operation Voltage at $f_{LO} = 965$ MHz



## Layout of 880 MHz to 85 MHz Down-Converter Application Board



**Figure 4 Layout of Application Board**

PCB - data: Glass fiber epoxy board (double sided),  $\epsilon_r = 4.8$ , thickness = 1.0 mm

## Characteristics of 880 MHz to 85 MHz Down-Converter Application Board

(Test conditions:  $V_D = 3.0$  V;  $f_{RF} = 880$  MHz;  $f_{LO} = 965$  MHz;  $P_{LO} = 0$  dBm;  $f_{IF} = 85$  MHz;  $T_A = 25$  °C;  $Z_O = 50$   $\Omega$ )

Parameter	Symbol	Value	Unit
Operating current	$I_{OP}$	4.9	mA
Conversion Loss	$L_C$	5.5	dB
3 <sup>rd</sup> Order Input Intercept Point	$IP_{3IN}$	+ 23.8	dBm
Return Loss (RF- /IF-Port)	RL	> 12	dB